

Preliminary TOSHIBA Transistor Silicon NPN Epitaxial Type (Darlington power transistor)

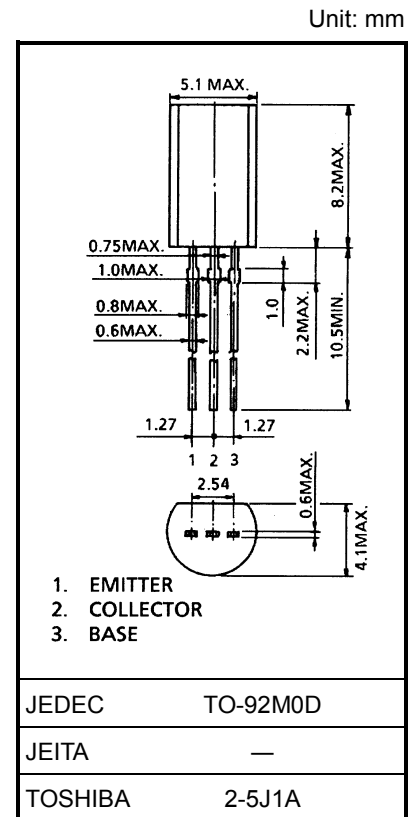
2SD2248

Hammer Drive, Pulse Motor Drive Applications
For Inductive Load Drive

- High DC current gain: $h_{FE} = 2000$ (min) ($V_{CE} = 2\text{ V}$, $I_C = 1\text{ A}$)
- Low saturation voltage: $V_{CE(sat)} = 1.5\text{ V}$ (max)
($I_C = 1\text{ A}$, $I_B = 1\text{ mA}$)
- Built-in zener diode between collector and base

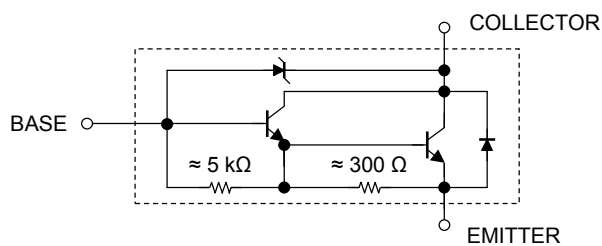
Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	80 ± 10	V
Collector-emitter voltage		V_{CEO}	80 ± 10	V
Emitter-base voltage		V_{EBO}	8	V
Collector current	DC	I_C	± 2	A
	Pulse	I_{CP}	± 3	
Base current		I_B	0.5	A
Collector power dissipation ($T_a = 25^\circ\text{C}$)		P_C	0.9	W
Junction temperature		T_j	150	$^\circ\text{C}$
Storage temperature range		T_{stg}	-55 to 150	$^\circ\text{C}$



Weight: 0.36 g (typ.)

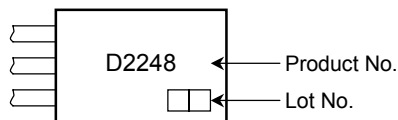
Equivalent Circuit



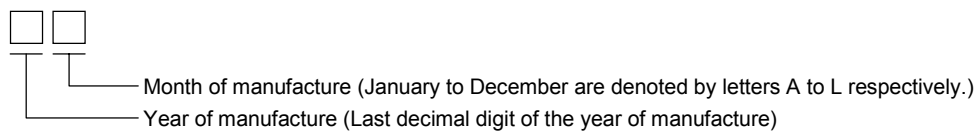
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		I_{CBO}	$V_{CB} = 60\text{ V}, I_E = 0$	—	—	10	μA
Emitter cut-off current		I_{EBO}	$V_{EB} = 8\text{ V}, I_C = 0$	0.8	—	4.0	mA
Collector-base breakdown voltage		$V_{(BR)CBO}$	$I_C = 100\ \mu\text{A}, I_E = 0$	70	80	90	V
Collector-emitter breakdown voltage		$V_{(BR)CEO}$	$I_C = 10\ \text{mA}, I_B = 0$	70	80	90	V
DC current gain		$h_{FE(1)}$	$V_{CE} = 2\text{ V}, I_C = 1\text{ A}$	2000	—	—	
Collector-emitter saturation voltage		$V_{CE(sat)}$	$I_C = 1\text{ A}, I_B = 1\text{ mA}$	—	—	1.5	V
Base-emitter saturation voltage		$V_{BE(sat)}$	$I_C = 1\text{ A}, I_B = 1\text{ mA}$	—	—	2.0	V
Emitter-collector forward voltage		V_{ECF}	$I_E = 1\text{ A}, I_B = 0$	—	1.2	2.0	V
Transition frequency		f_T	$V_{CE} = 2\text{ V}, I_C = 0.5\text{ A}$	—	100	—	MHz
Collector output capacitance		C_{ob}	$V_{CB} = 10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	20	—	pF
Unclamped inductive load energy		$E_{S/B}$	$L = 10\text{ mH}, I_C = 1.2\text{ A}, I_B = \pm 50\text{ mA}$	7.2	—	—	mJ
Switching time	Turn-on time	t_{on}	<p>$I_{B1} = -I_{B2} = 1\text{ mA}, \text{duty cycle} \leq 1\%$</p>	—	0.2	—	μs
	Storage time	t_{stg}		—	4.0	—	
	Fall time	t_f		—	0.6	—	

Marking



Explanation of Lot No.



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